

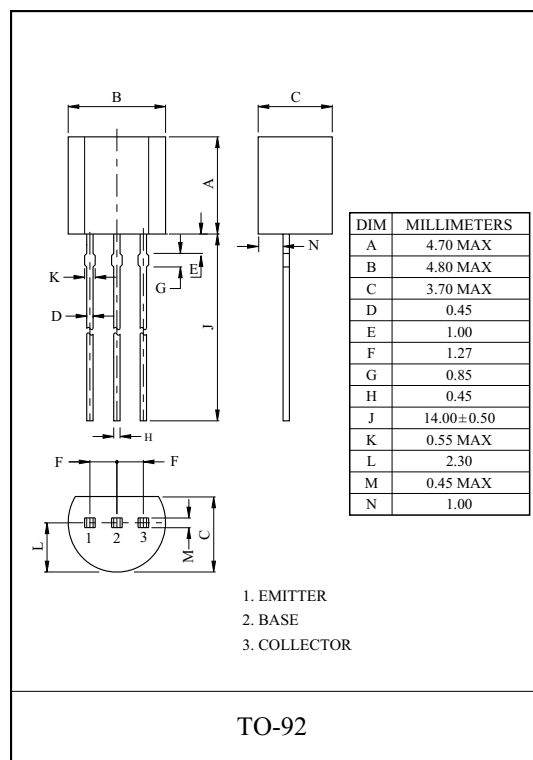
LOW FREQUENCY AMPLIFIER

FEATURES

- Collector-Base Voltage : $V_{CBO}=-60V$.
- Complementary to KTC815.

MAXIMUM RATING (Ta=25℃)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	-60	V
Collector-Emitter Voltage	V_{CEO}	-45	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-200	mA
Collector Power Dissipation	P_C	625	mW
Junction Temperature	T_j	150	℃
Storage Temperature Range	T_{stg}	-55 ~ 150	℃



ELECTRICAL CHARACTERISTICS (Ta=25℃)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=-100\mu A, I_E=0$	-60	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=-10mA, I_B=0$	-45	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=-10\mu A, I_C=0$	5	-	-	V
Collector Cut-off Current	I_{CBO}	$V_{CB}=-45V, I_E=0$	-	-	-0.1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=-3V, I_C=0$	-	-	-0.1	μA
DC Current Gain	h_{FE} (Note)	$V_{CE}=-1V, I_C=-50mA$	70	-	240	
Base-Emitter Voltage	V_{BE}	$V_{CE}=-1V, I_C=-10mA$	-0.6	-0.65	-0.9	V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-150mA, I_B=-15mA$	-	-0.25	-0.5	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=-150mA, I_B=-15mA$	-	-0.9	-1.2	V
Transition Frequency	f_T	$V_{CE}=-10V, I_C=-10mA$	100	-	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=-10V, I_E=0, f=1MHz$	-	6	-	pF

Note : h_{FE} Classification O:70~140, Y:120~240

